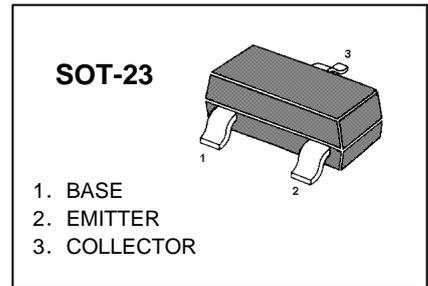


# BC846... TRANSISTOR (NPN)

## FEATURE

Ideally suited for automatic insertion

For Switching and AF Amplifier Applications



## MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter		Value	Units
$V_{\text{CBO}}$	Collector-Base Voltage	BC846	80	V
		BC847	50	
		BC848	30	
$V_{\text{CEO}}$	Collector-Emitter Voltage	BC846	65	V
		BC847	45	
		BC848	30	
$V_{\text{EBO}}$	Emitter-Base Voltage		6	V
$I_{\text{C}}$	Collector Current –Continuous		0.1	A
$P_{\text{C}}$	Collector Power Dissipation		200	mW
$T_{\text{J}}$	Junction Temperature		150	$^{\circ}\text{C}$
$T_{\text{stg}}$	Storage Temperature		-65-150	$^{\circ}\text{C}$

## DEVICE MARKING

BC846A=1A; BC846B=1B;

BC847A=1E; BC847B=1F; BC847C=1G;

BC848A=1J; BC848B=1K; BC848C=1L

**ELECTRICAL CHARACTERISTICS (T<sub>amb</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	BC846 BC847 BC848	V <sub>CBO</sub>	I <sub>C</sub> = 10μA, I <sub>E</sub> =0	80 50 30		V
Collector-emitter breakdown voltage	BC846 BC847 BC848	V <sub>CEO</sub>	I <sub>C</sub> = 10mA, I <sub>B</sub> =0	65 45 30		V
Emitter-base breakdown voltage		V <sub>EBO</sub>	I <sub>E</sub> = 10μA, I <sub>C</sub> =0	6		V
Collector cut-off current	BC846 BC847 BC848	I <sub>CBO</sub>	V <sub>CB</sub> =70 V, I <sub>E</sub> =0 V <sub>CB</sub> =50 V, I <sub>E</sub> =0 V <sub>CB</sub> =30 V, I <sub>E</sub> =0		0.1	μA
Collector cut-off current	BC846 BC847 BC848	I <sub>CEO</sub>	V <sub>CE</sub> =60 V, I <sub>B</sub> =0 V <sub>CE</sub> =45 V, I <sub>B</sub> =0 V <sub>CE</sub> =30 V, I <sub>B</sub> =0		0.1	μA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> =5 V, I <sub>C</sub> =0		0.1	μA
DC current gain	BC846A,847A,848A BC846B,847B,848B BC847C,BC848C	h <sub>FE</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 2mA	110 200 420	220 450 800	
Collector-emitter saturation voltage		V <sub>CE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> = 5mA		0.5	V
Base-emitter saturation voltage		V <sub>BE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> = 5mA		1.1	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10mA f=100MHz	100		MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		4.5	pF

# Typical Characteristics

# BC846A,B;BC847A, B, C;BC848A, B, C

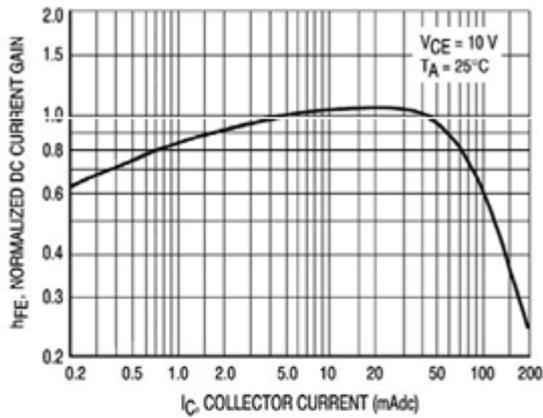


Figure 1. Normalized DC Current Gain

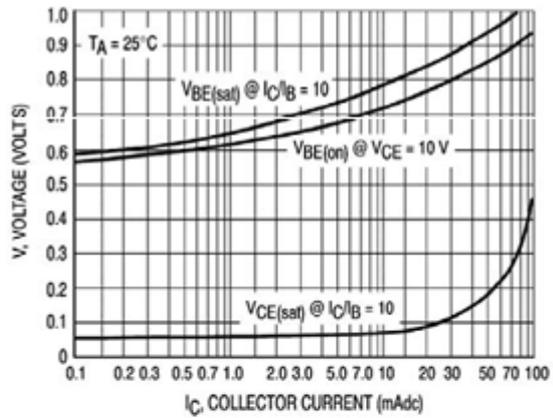


Figure 2. "Saturation" and "On" Voltages

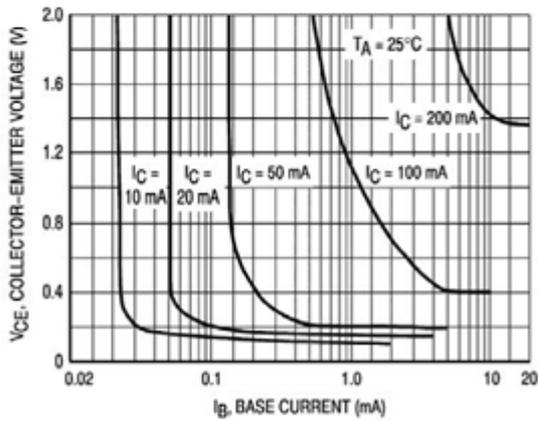


Figure 3. Collector Saturation Region

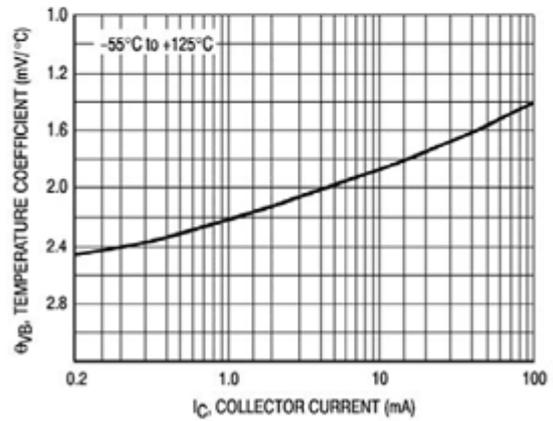


Figure 4. Base-Emitter Temperature Coefficient

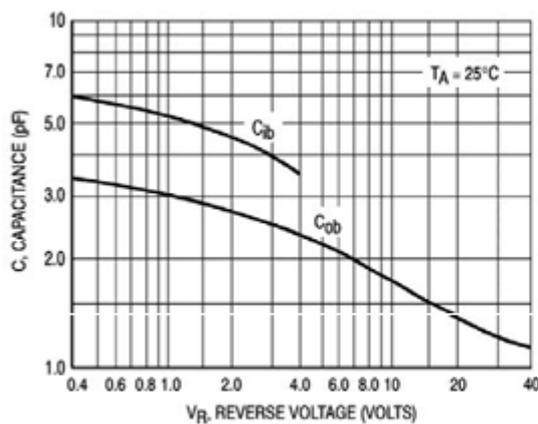


Figure 5. Capacitances

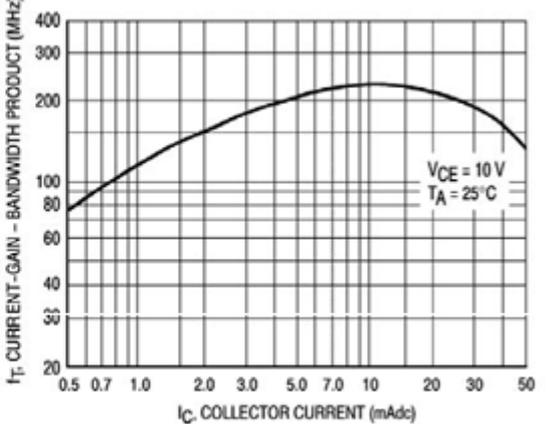


Figure 6. Current-Gain - Bandwidth Product

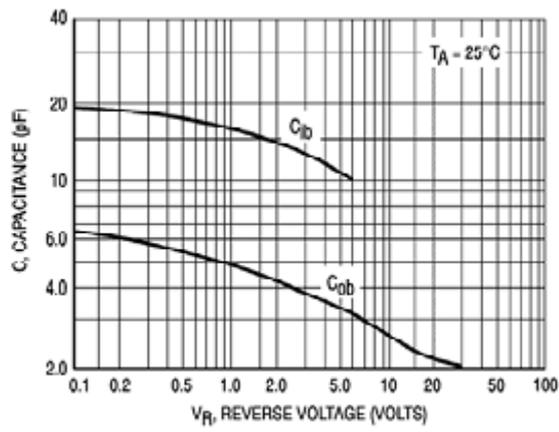


Figure 11. Capacitance

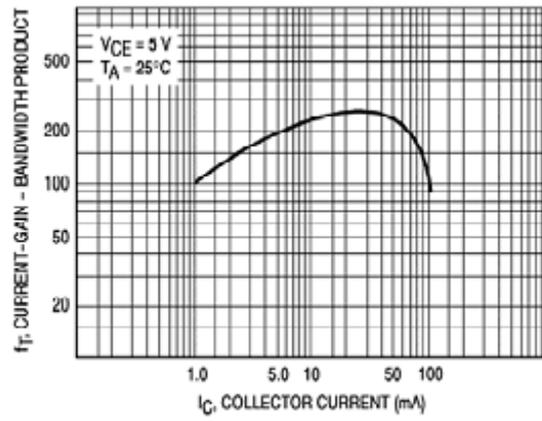
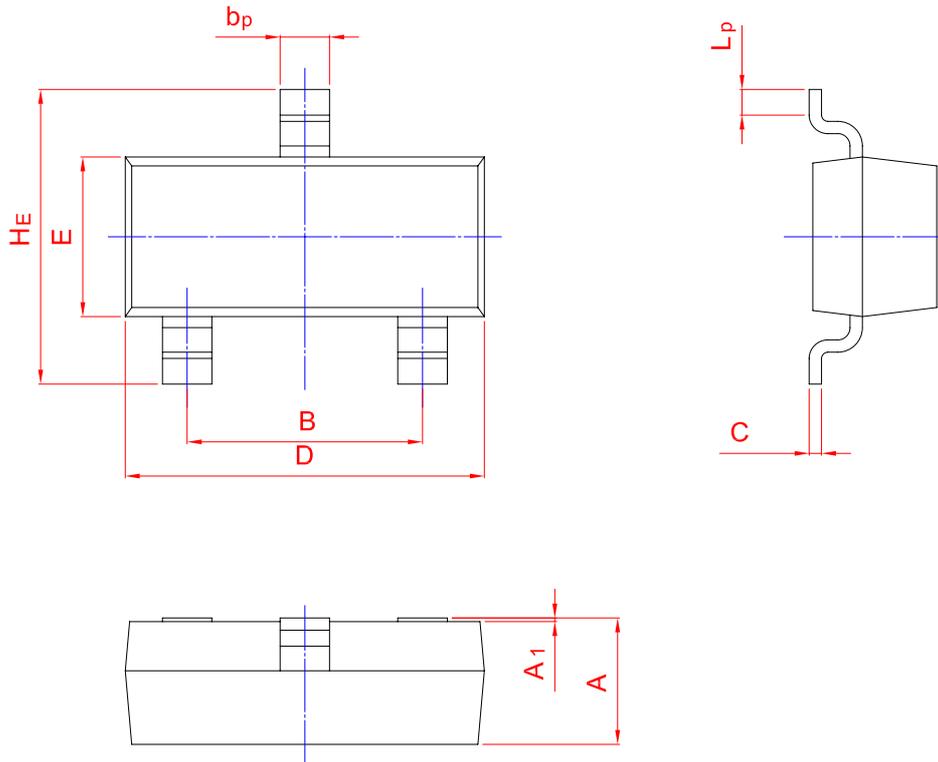
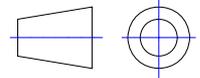


Figure 12. Current-Gain - Bandwidth Product

# PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b <sub>p</sub>	C	D	E	H <sub>ε</sub>	A <sub>1</sub>	L <sub>p</sub>
mm	1.40	2.04	0.50	0.19	3.10	1.65	3.00	0.100	0.50
	0.95	1.78	0.35	0.08	2.70	1.20	2.20	0.013	0.20